



An Ultrafast and Robust BaF_2 Calorimeter for EIC

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April 6, 2018



Introduction



- Fermilab is building a undoped CsI calorimeter for the Mu2e-I experiment, which is featured with 30 ns scintillation and surviving ionization dose up to 100 krad and hadron fluence up to $10^{12}/\text{cm}^2$. A radiation level exceeding 100 krad is expected by the proposed Mu2e-II, so BaF_2 is being considered.
- With sub-ns fast scintillation and excellent radiation hardness beyond 100 Mrad and hadrons, BaF_2 promises a very fast and robust calorimeter.
- There are several approaches to handle 600 ns slow scintillation in BaF_2 : solar blind photodetector and selective doping in crystal.
- Effective suppression of the slow component has been achieved in yttrium doped BaF_2 crystals.
- Mass production capability of BaF_2 exists in industry:
 - BGRI (China), Incrom (Russia) and SICCAS (China);
 - Hellma (Germany).



Fast Inorganic Scintillators



	LSO/LYSO	GSO	YSO	CsI	BaF ₂	CeF ₃	CeBr ₃	LaCl ₃	LaBr ₃	Plastic scintillator (BC 404) ^①
Density (g/cm ³)	7.4	6.71	4.44	4.51	4.89	6.16	5.23	3.86	5.29	1.03
Melting point (°C)	2050	1950	1980	621	1280	1460	722	858	783	70 [#]
Radiation Length (cm)	1.14	1.38	3.11	1.86	2.03	1.7	1.96	2.81	1.88	42.54
Molière Radius (cm)	2.07	2.23	2.93	3.57	3.1	2.41	2.97	3.71	2.85	9.59
Interaction Length (cm)	20.9	22.2	27.9	39.3	30.7	23.2	31.5	37.6	30.4	78.8
Z value	64.8	57.9	33.3	54	51.6	50.8	45.6	47.3	45.6	5.82
dE/dX (MeV/cm)	9.55	8.88	6.56	5.56	6.52	8.42	6.65	5.27	6.9	2.02
Emission Peak ^a (nm)	420	430	420	420 310	300 220	340 300	371	335	356	408
Refractive Index ^b	1.82	1.85	1.8	1.95	1.5	1.62	1.9	1.9	1.9	1.58
Relative Light Yield ^{a,c}	100	45	76	4.2 1.3	42 4.8	8.6	99	15 49	153	35
Decay Time ^a (ns)	40	73	60	30 6	650 0.6	30	17	570 24	20	1.8
d(LY)/dT ^d (%/°C)	-0.2	-0.4	-0.1	-1.4	-1.9 0.1	~0	-0.1	0.1	0.2	~0

a. Top line: slow component, bottom line: fast component.

b. At the wavelength of the emission maximum.

c. Relative light yield normalized to the light yield of LSO

d. At room temperature (20°C)

#. Softening point

1. <http://www.detectors.saint-gobain.com/Plastic-Scintillator.aspx>

http://pdg.lbl.gov/2008/AtomicNuclearProperties/HTML_PAGES/216.html

The 0.6 ns fast scintillation in BaF₂ promises a very fast crystal calorimeter to face the challenge of high event rate expected by future HEP experiments at the intensity frontier

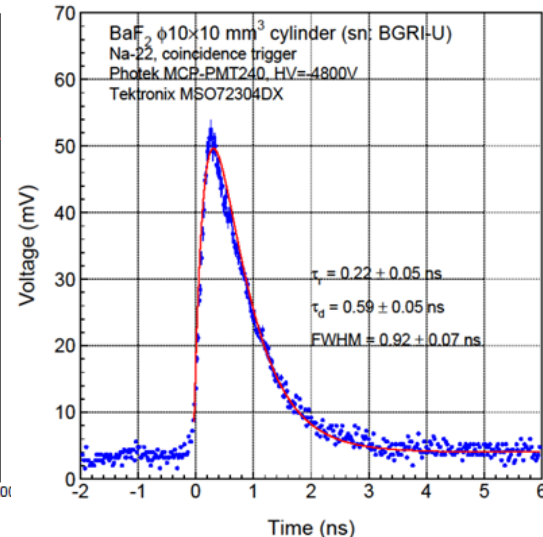
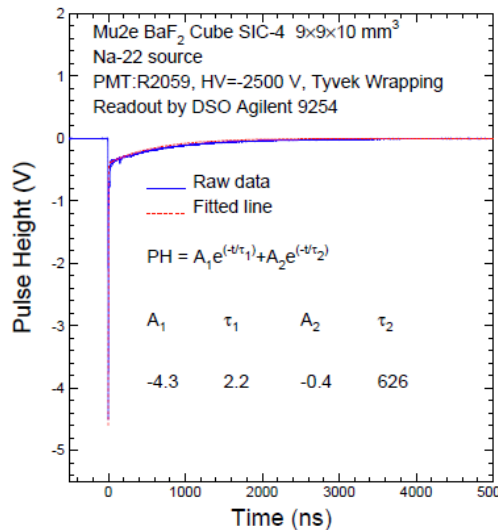
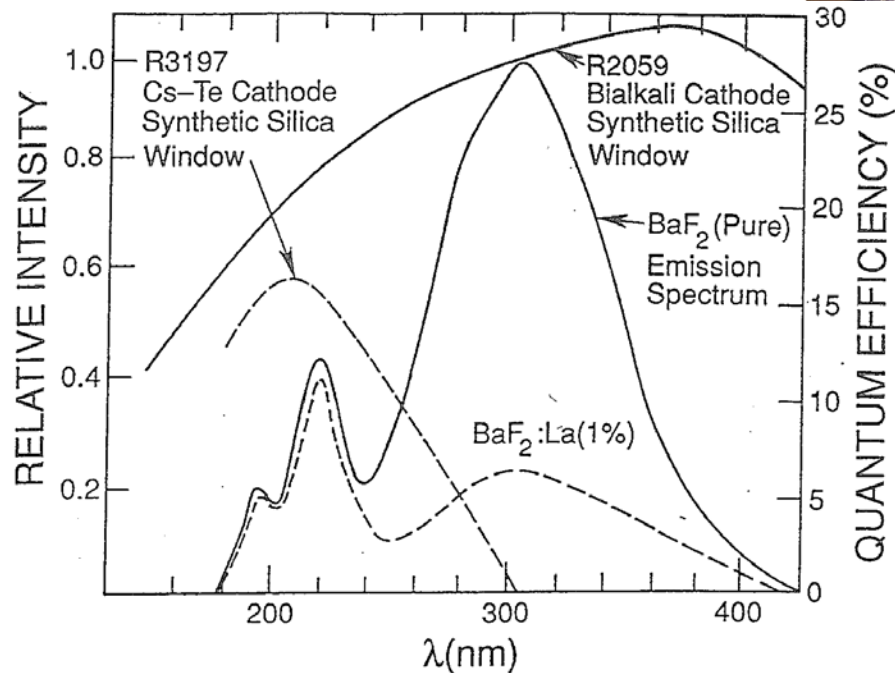


Fast and Slow Light from BaF₂



The fast component at 220 nm with 0.6 ns decay time has a similar LO as undoped CsI.

Spectroscopic selection of fast component may be realized by solar blind photocathode and/or selective doping.



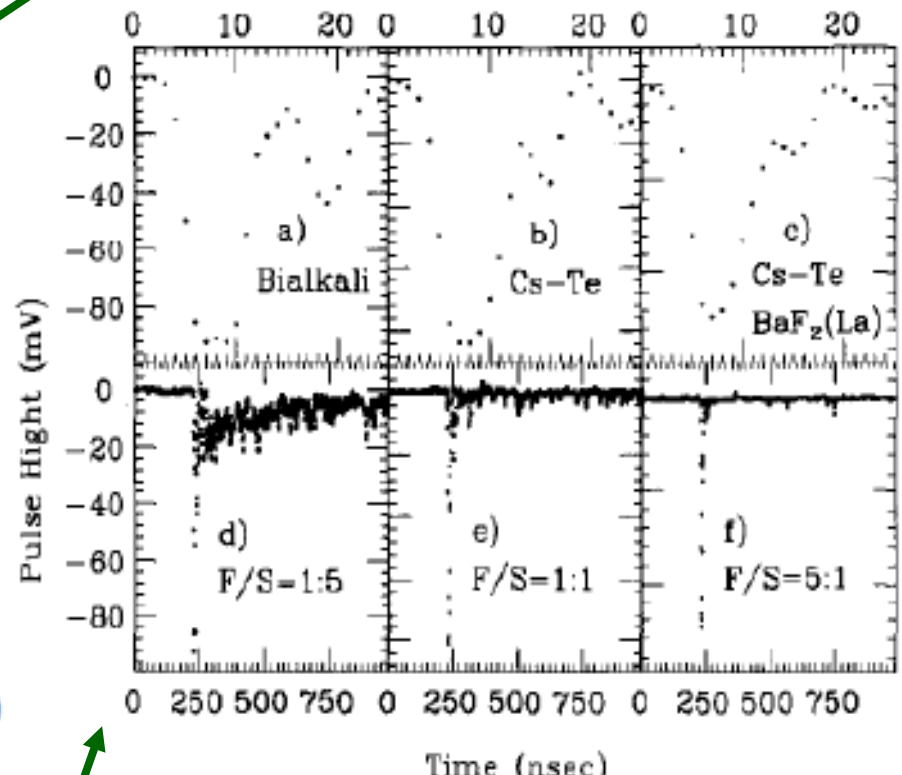
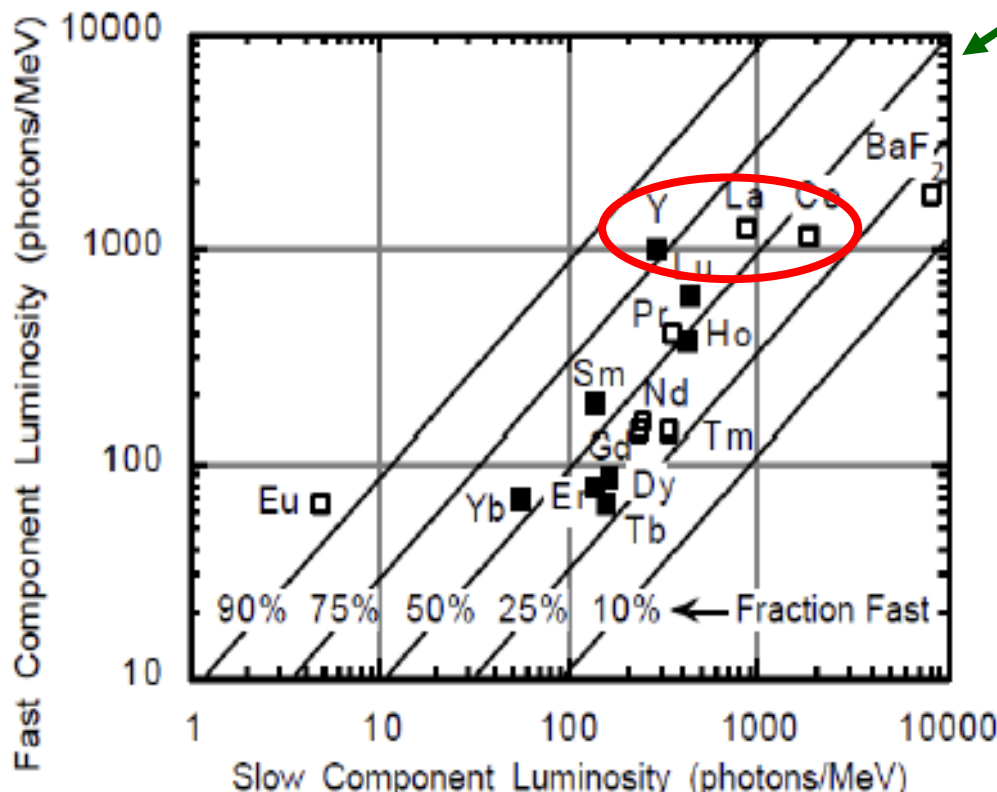


Slow Suppression: Doping & Readout



Slow component may be suppressed by RE doping: Y, La and Ce

B.P. SOBOLEV et al., "SUPPRESSION OF BaF₂ SLOW COMPONENT OF X-RAY LUMINESCENCE IN NON-STOICHIOMETRIC Ba_{0.9R0.1}F₂ CRYSTALS (R=RARE EARTH ELEMENT)," *Proceedings of The Material Research Society: Scintillator and Phosphor Materials*, pp. 277-283, 1994.



Solar-blind cathode (Cs-Te) + La doping achieved high F/S

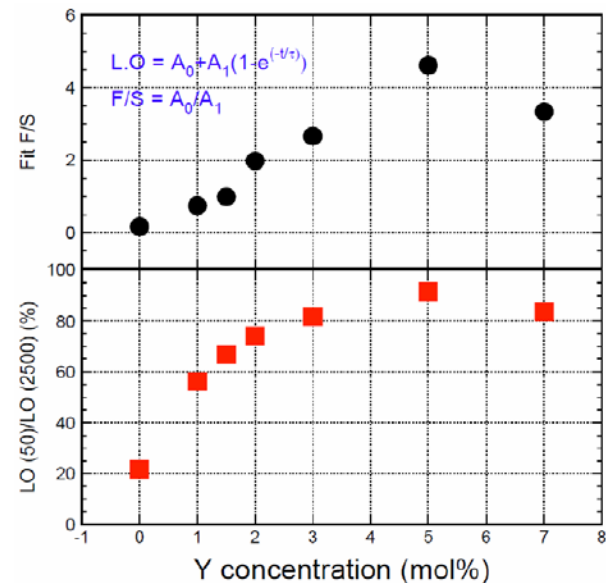
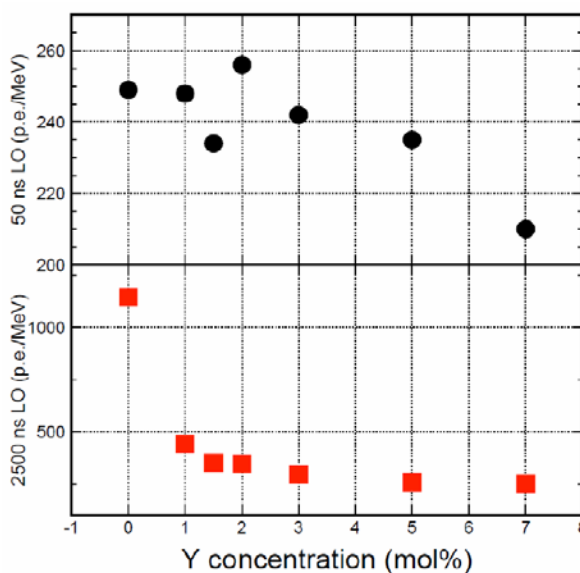
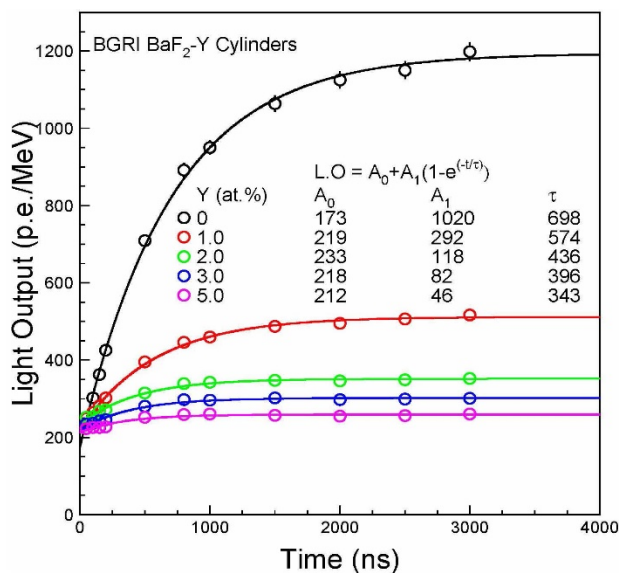
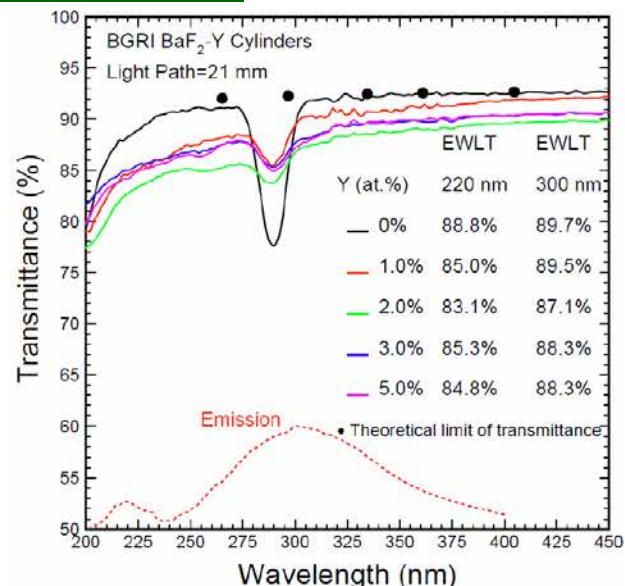
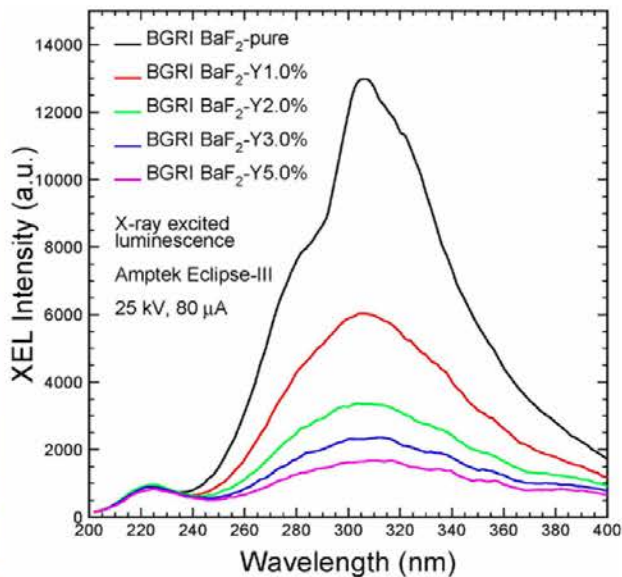
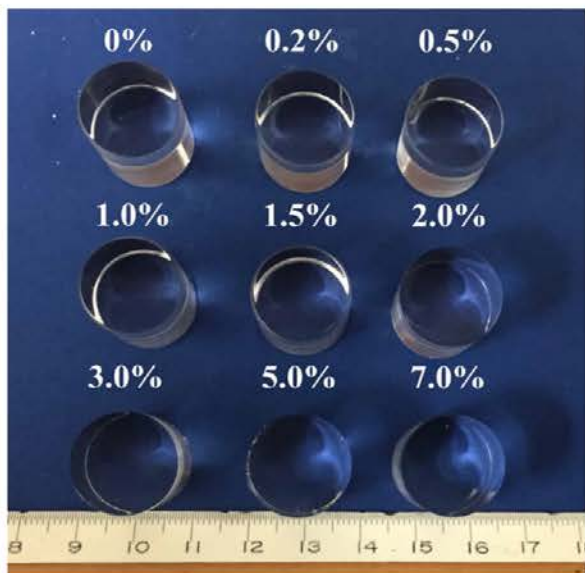
Z. Y. Wei, R. Y. Zhu, H. Newman, and Z. W. Yin, "Light Yield and Surface-Treatment of Barium Fluoride-Crystals," *Nucl Instrum Meth B*, vol. 61, pp. 61-66, Jul 1991.



Yttrium Doping in BaF₂

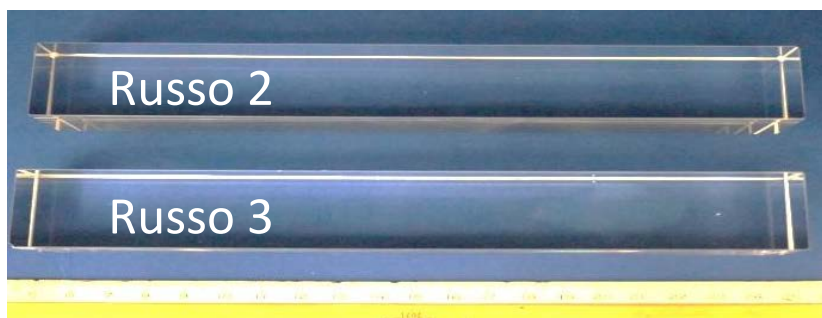


Significant increase in F/S ratio observed





BGRI/Incrom/SIC BaF₂ Samples



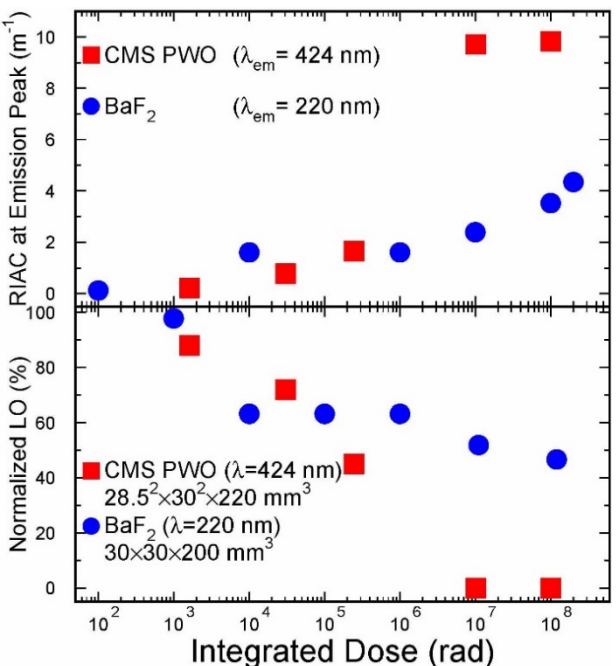
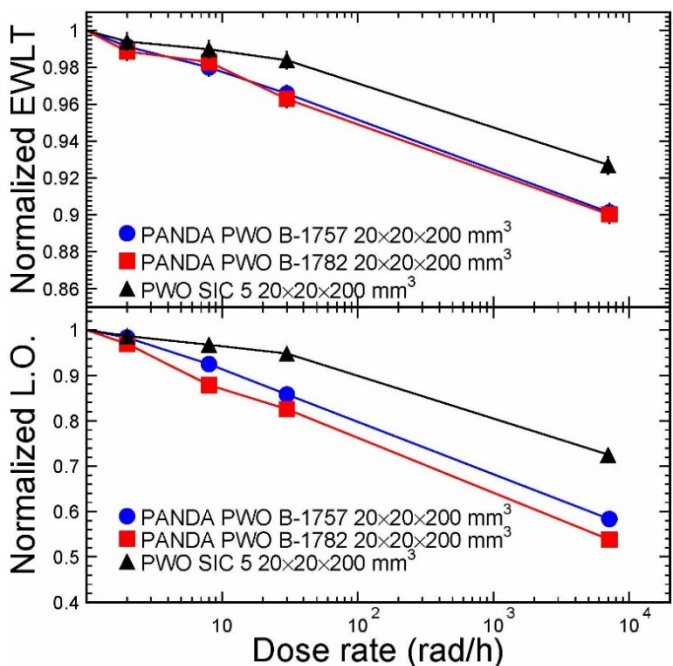
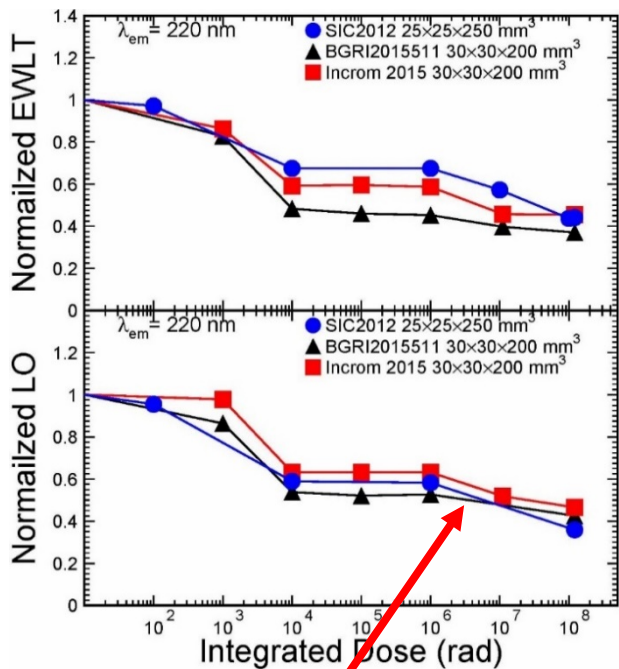
ID	Vendor	Dimension (mm ³)	Polishing
SIC 1-20	SICCAS	30x30x250	Six faces
BGRI-2015 D, E, 511	BGRI	30x30x200	Six faces
Russo 2, 3	Incrom	30x30x200	Six faces



Ionization Dose: BaF₂ and PWO



Dose rate dependent damage in PWO
Good radiation hardness in BaF₂ up to 100 Mrad



40% fast scintillation light remains after 120 Mrad ionization dose

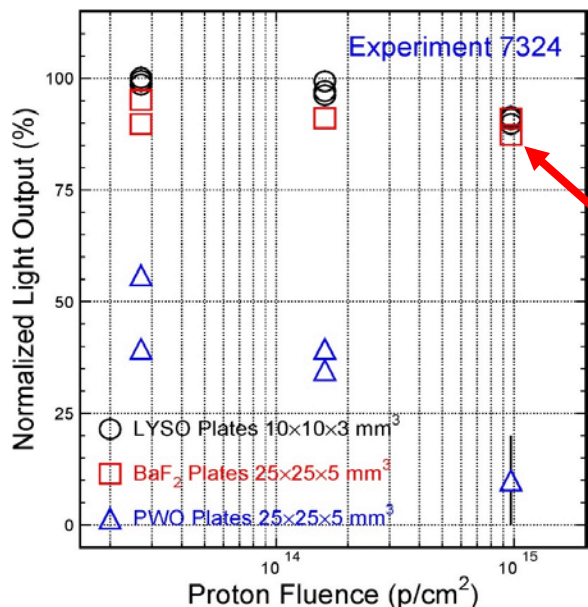
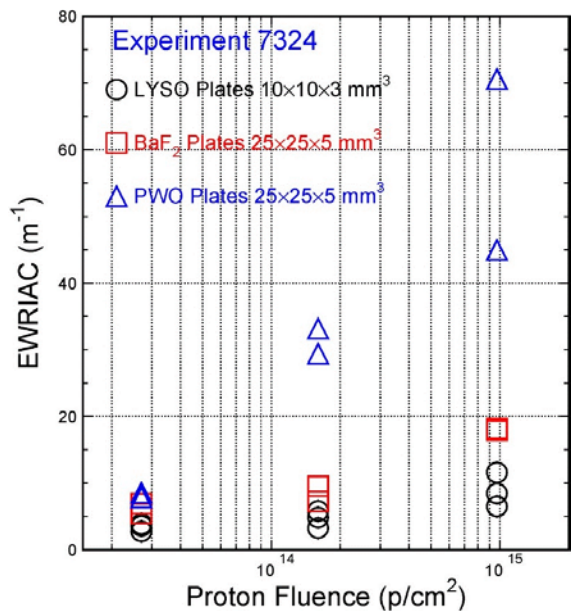
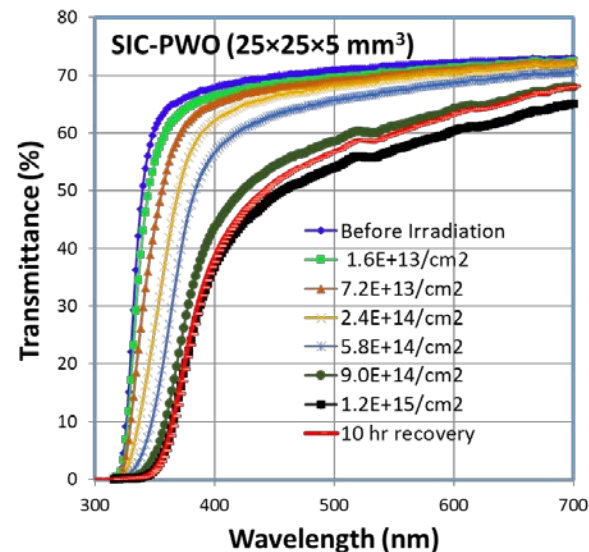
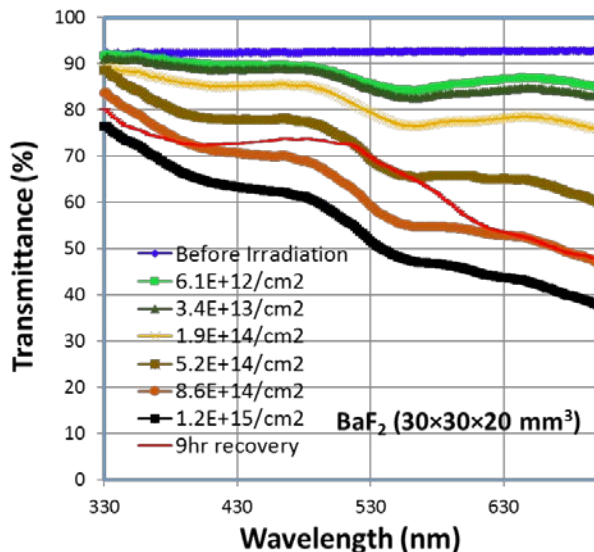
Fan Yang et al., IEEE TNS 64 (2017) 665-672



Protons: LYSO/BaF₂/PWO at LANSCE



A Hellma BaF₂ of 2 cm and a SIC PWO of 5 mm were irradiated up to 1.2×10^{15} p/cm² by 800 MeV protons at the blue room of LANSCE with transmittance measured *in-situ*.



LYSO, BaF₂ and PWO plates of 3, 5 and 5 mm were also irradiated up to 1×10^{15} p/cm². Excellent radiation hardness observed in LYSO and BaF₂, but not PWO.

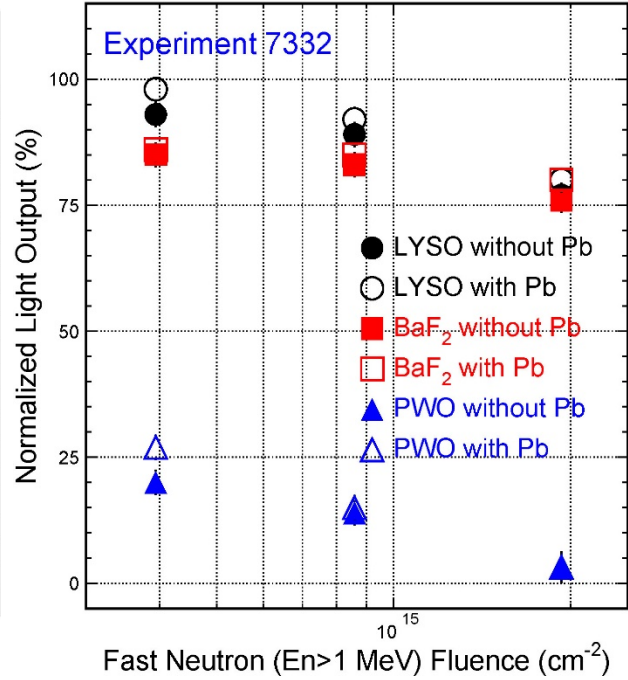
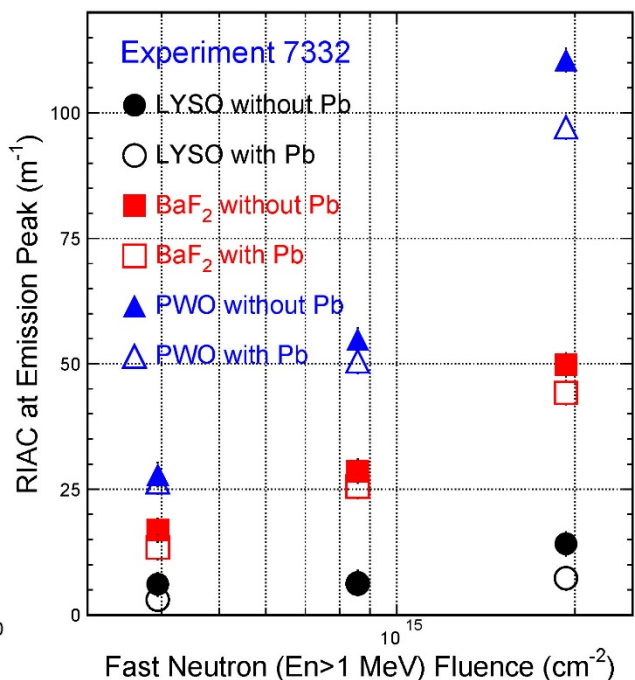
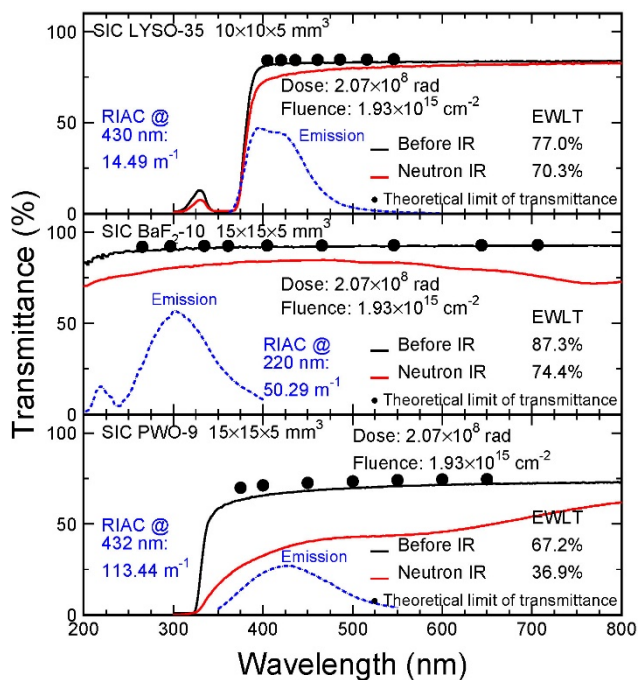
Proton-Induced Radiation Damage in BaF₂, LYSO and PWO Crystal Scintillators, IEEE TNS 65 (2018) Digital Object Identifier 10.1109/TNS.2018.2808841



Neutrons: LYSO/BaF₂/PWO at LANSCE



LYSO, BaF₂ and PWO plates of 5 mm were irradiated up to 2×10^{15} n/cm² in three steps at the East Port of LANSCE



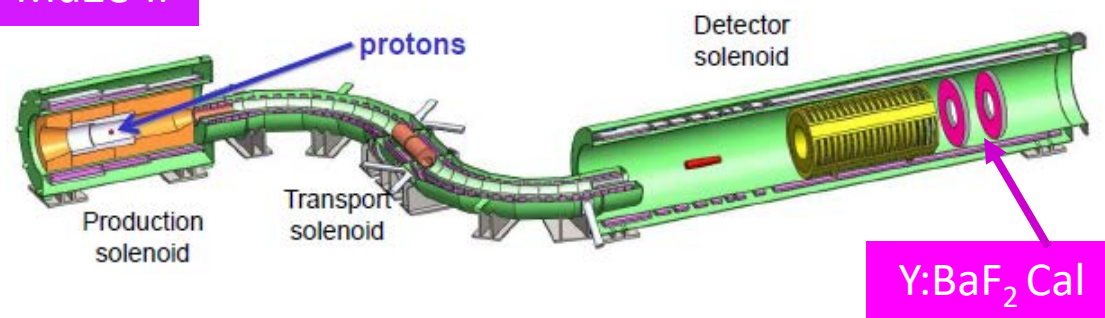
Excellent radiation hardness observed in LYSO and BaF₂, but not PWO

Ultrafast Barium Fluoride Applications

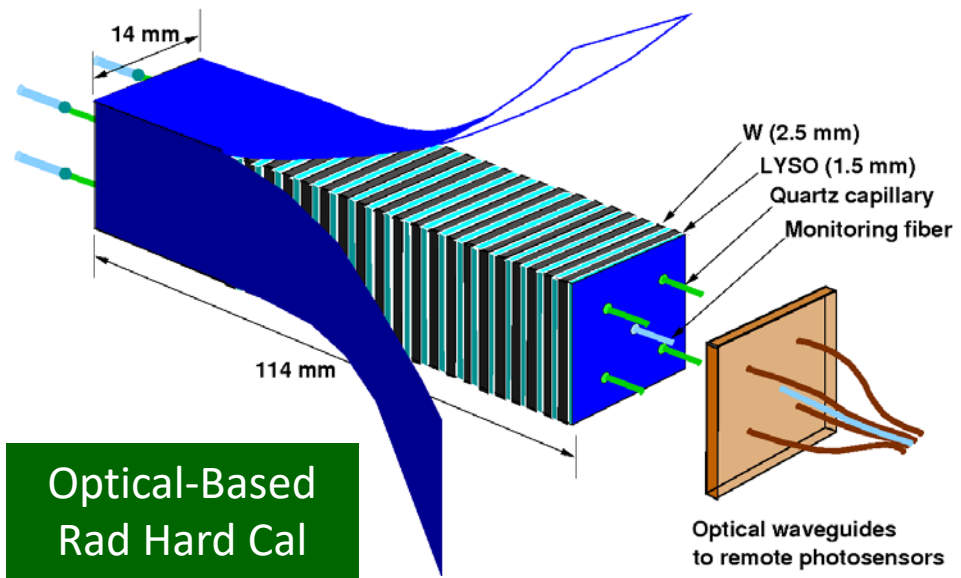


With sub-ns decay time/FWHM pulse width and excellent radiation hardness BaF_2 is an ultrafast inorganic scintillator for future HEP calorimeters at the energy and intensity frontiers

Mu2e-II

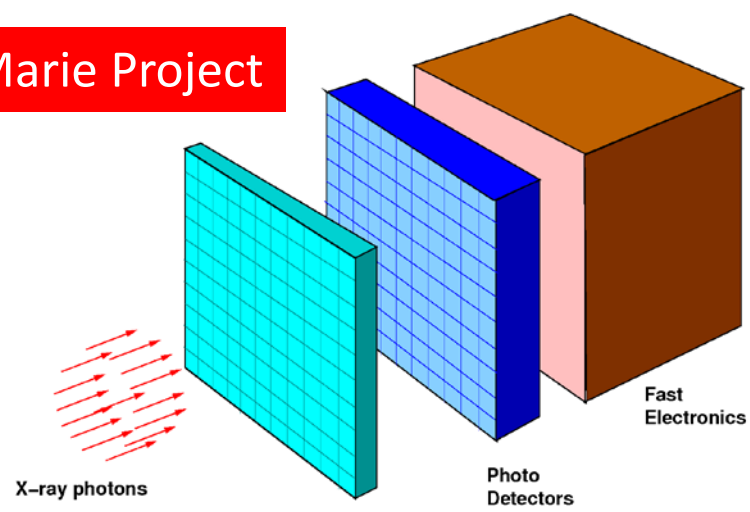


Y:BaF₂ is also attractive for an ultrafast front imager for the FEL based GHz hard x-ray imaging



Optical-Based Rad Hard Cal

Marie Project



Y:BaF₂ Screen



Summary



- ❑ Commercially available BaF₂ crystals provide sufficient fast light with 0.6 ns decay time and excellent radiation hardness against ionization dose and (100 Mrad) and hadrons ($2 \times 10^{15}/\text{cm}^2$). They promise an ultrafast and robust calorimeter in a severe radiation environment.
- ❑ Yttrium doping in BaF₂ crystals significantly improves the F/S ratio without using selected readout. R&D is continued to develop BaF₂ crystals along this line.
- ❑ To be investigated is photodetectors with DUV response, e.g. Hamamatsu SiPM, diamond photodetector and solar-blind photodetector.
- ❑ It would be a joint effort with the HEP community if the EIC group chooses to pursue this novel crystal calorimeter.

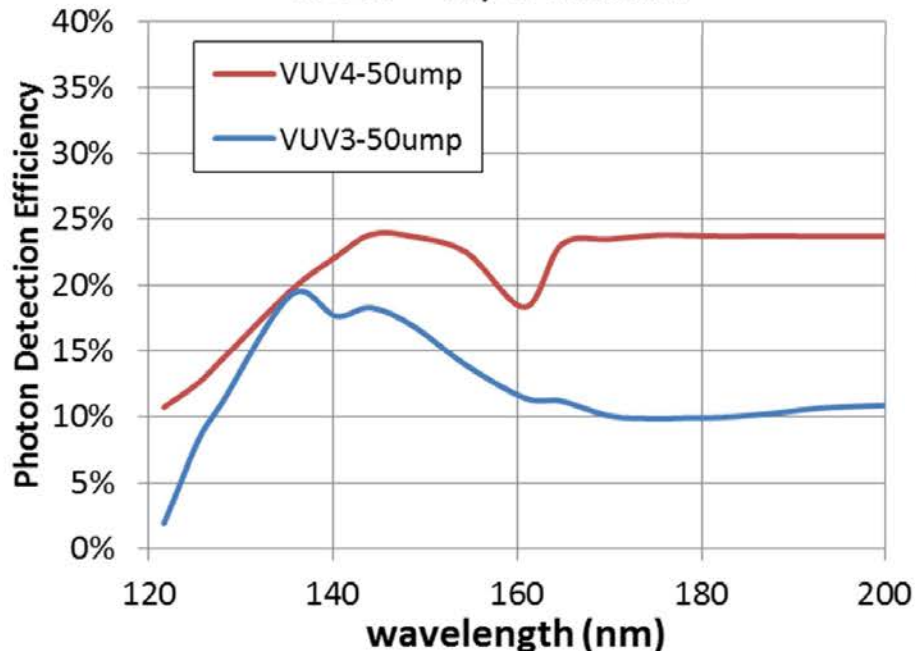


Hamamatsu S13371-6050CQ-02

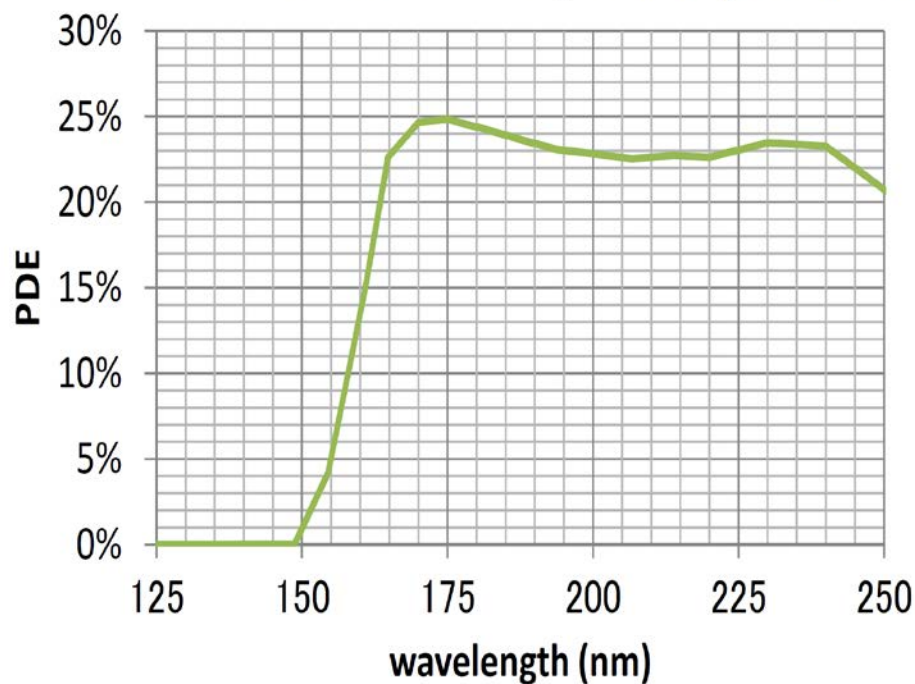


SiPM with VUV response is available: QE = 22% at 220 nm

PDE measurement data
Vover = 4V, in vacuum



S13371-6050CQ-02 PDE (Vover = 4V)





Diamond Photodetector



E. Monroy, F. Omnes and F. Calle, "Wide-bandgap semiconductor ultraviolet photodetectors, IOPscience 2003 Semicond. Sci. Technol. 18 R33

E. Pace and A. De Sio, "Innovative diamond photo-detectors for UV astrophysics", Mem. S.A.It. Suppl. Vol. 14, 84 (2010)

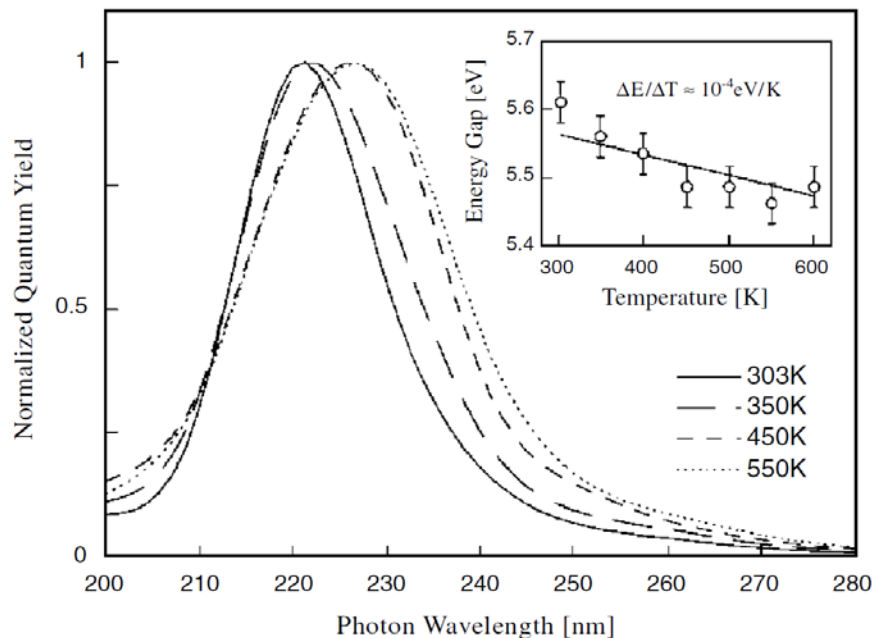


Figure 6. Quantum efficiency of diamond photoconductors at different temperatures and Arrhenius plot of the peak value (inset). (From [Sal00].)

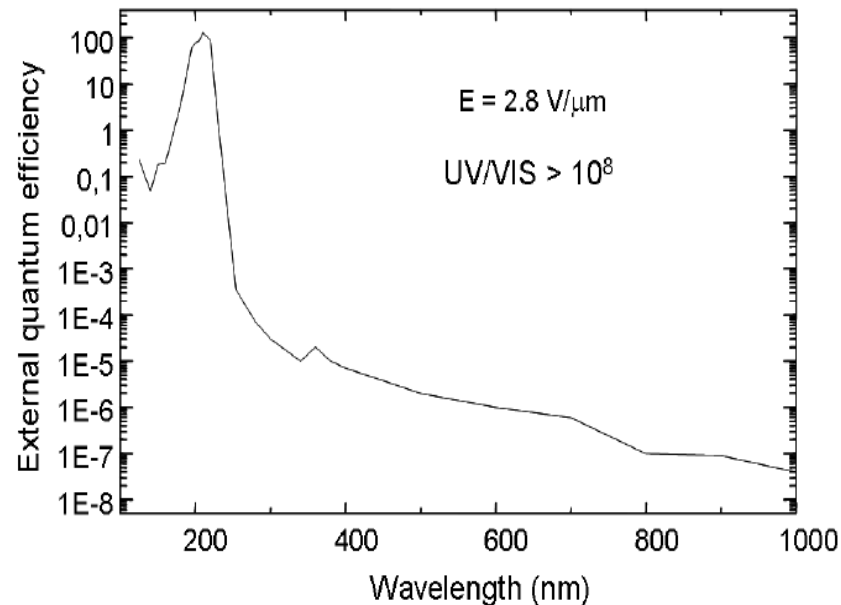


Fig.4. External quantum efficiency extended to visible and near infrared wavelength regions. The